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DESIGN OF INTERLEAVED MULTILAYER ROSEN TYPE PIEZOELECTRIC TRANSFORMER FOR HIGH VOLTAGE DC/DC APPLICATIONS

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Abstract
Research and development within piezoelectric transformer (PT) based converters are rapidly increasing as the technology is maturing and starts to prove its capabilities. Especially for high voltage and high step-up applications, PT based converters have demonstrated good performance and DC/AC converters are widely used commercially. The availability of PT based converters for DC/DC applications are very limited and are not that developed yet. In this paper an interleaved multi layer Rosen-type PT for high step-up and high output voltage is developed, for driving a 2.5kV dielectric electro active polymer actuator [17]. The targeted application utilises an inductor-less half-bridge driving topology, where the reward of eliminating the series inductor is a reduction in component count, size and price. The absence of a series inductance calls for other means to avoid large hard switching losses and obtain soft switching capabilities. This can be achieved by utilising an advantageous PT structure, which is the main advantage of the interleaved Rosen-type PT. Furthermore the design should be further optimised, in order to achieve soft switching capability. The goal of this paper is to develop a soft switching optimised PT, capable of generating output voltages higher than 2kV from a 24V supply voltage. Furthermore finite element method (FEM) has been the main tool through the PT development.

1 Introduction
The piezoelectric transformer (PT) was originally developed by Rosen in 1957 [16] and utilises piezoelectric ceramics to convert electrical energy through mechanical vibrations. PT based converters have demonstrated good performance and DC/AC converters are widely used commercially, especially for high step-up and high voltage (HV) applications, like LCD backlighting. But they are still limited to these simple applications (with a constant and high frequency AC load) and the availability of PT based converters for DC/DC applications are very limited and are not that developed yet. However new applications, like electro active polymer (EAP) actuators [5][17], require a high and adjustable DC voltage and calls for DC/DC converters of high step-up and high output voltage.

EAP devices are based on polymer materials and change shape as a result of the electrostatic forces, generated by an applied voltage. The EAP technology has a wide potential in applications such as surgical tools, grippers for material handling and valve actuators for example. The EAP material is essentially just a thin film of polymer with an electrode on each side. It can be modulated as a HV capacitor with a very low leakage current and the force generated by the EAP is related to the applied voltage. The voltage required is dependent among others by the thickness of the EAP film. The EAP technology available today has a film thickness of around 80 µm [5][17], it has a maximum working voltage of 2.5 kV and requires a voltage above 2kV to fully utilise it as an actuator.

Figure 1: Schematical diagram of the inductor-less half-bridge topology and the PT equivalent lumped parameter model.
To date, conventional converters utilize electromagnetic components and are the only available HV sources for driven EAP actuators. However these HV converters have poor efficiency, are bulky and provide limited opportunities for miniaturization. PT based converters, on the other hand, are compact and offers high efficiency, especially for high step-up applications. This makes the PT based converter the perfect match for the EAP technology.

In the last decade a lot of research in to the area of PT’s has improved Rosen’s fist PT and new types of PT’s have been developed [4][8][11][14][18]. I this paper an interleaved multi layer Rosen-type PT for high step-up and high output voltage is developed, for driving a 2.5kV EAP actuator [17]. The specific EAP actuator application is described in more detail in [1] and is similar to the one in [3]. Figure 1 illustrates a schematic diagram of the converter, which utilises an inductor-less half bridge topology [2][13]. An inductor in series with the PT is usually necessary, in order to achieve soft switching and efficient operation. The absence of a series inductance calls for other means to avoid large hard switching losses and obtain soft switching capability.

The PT design is quite similar to the one presented in [18], but differs with the polarization of the secondary being in the same direction, as well as it has been optimised for soft switching. Meaning that it is capable of operating the half-bridge under zero voltage switching (ZVS), without any added inductance in series with the PT. The operational vibration resonance is along the longitudinal direction and is generated through the electromechanical coupling factors $k_{31}$ and $k_{33}$, primary and secondary respectively. In Figure 4 a

The PT resembles a distributed network, but for simplicity and mathematical representation, only the resonance mode of interest is modelled [9][10][11]. One of the most used PT models is the lumped parameter model, which was derived by Mason in 1942 [12] and is illustrated in Figure 2.

![Figure 2: Lumped parameter model](image)

The model is basically a LCC resonance tank and the behaviour of a PT based converter is also quite similar to a traditional resonance converter [6].

### 2.1 Piezoelectric transformer design

The PT developed for this application is essential an interleaved multi layer Rosen-type, meaning that the primary section of the PT has been interleaved into the secondary section. Figure 3 illustrates the structure of the PT, which consists of a primary section with 12 layers, of 166µm in thickness and one split secondary layer. For simplicity the figure only shows two primary layers and the arrows indicate the polarization direction. The PT is build using tape casting technology and the NCE46 piezoelectric material [15]. The PT has the dimensions of 25mm x 10mm x 2mm, but PT’s of 20mm, 30mm and 35mm in length were also designed and produced in the same process.

![Figure 3: The interleaved multi layer Rosen-type PT structure](image)

The PT design is quite similar to the one presented in [18], but differs with the polarization of the secondary being in the same direction, as well as it has been optimised for soft switching. Meaning that it is capable of operating the half-bridge under zero voltage switching (ZVS), without any added inductance in series with the PT. The operational vibration resonance is along the longitudinal direction and is generated through the electromechanical coupling factors $k_{31}$ and $k_{33}$, primary and secondary respectively. In Figure 4 a
FEM simulation of the operational vibration resonance is shown. The PT operates in its first longitudinal mode shape and it can be seen it has a nodal line in the center of the structure.

Figure 4: FEM simulation of the PT, operating in the first longitudinal mode shape, at 65.1 kHz. The colouring illustrates the total displacement, where dark colours refer to a low displacement and light colours to a high displacement, as the colour bar indicates.

One of the drawbacks of this design, for this application, is the split secondary. This results in a differential output voltage symmetrical around ground, which complicates the electronics somewhat. One could polarise the two half secondary layers in opposite directions, which results in a two layer secondary structure, obtaining a common voltage potential with reference to ground, as in [18]. But this approach would also divide the gain by two, because of two secondary layers, of half the thickness, instead of one full thickness secondary. For this application we need a very high gain, so the extra effort in the electronic is rewarded with a doubling in gain.

2.2 Piezoelectric transformer development

The major part of the development has been performed through iterative FEM simulations, where the two main design criteria have been a high gain and the capability of inductor-less operation. In order to utilise an inductor-less topology, the PT should posses soft switching capabilities. This is achieved through the relative location and size of the primary section. Furthermore the PT is operated slightly above the resonance frequency, where the series resonance network becomes inductive and contains enough resonating energy, to charge and discharge the input capacitance $C_d$. The interleaving of the primary section is the main advantage of this design, as this increases the soft switching capability. This is due to the placement right in the middle of the stress curve, which is a half-wave sine wave for the first resonance mode. Furthermore the primary section size has been optimised in order obtain soft switching capability.

Rosen-type PT’s has a native high gain, which is good for this application. The gain is mainly determined by the thickness of the primary layers, but of course the primary section size also affects the gain.

From the lumped parameters some more general performance properties of the PT can be calculated, as the soft switching factor, matched load, power in matched load, gain and efficiency.

The load is usually matched to the output capacitance $C_d$ of the PT, Equation (1), or the other way around, because this maximises the power transfer of the resonance network to the load. Furthermore all the following performance properties assume a matched load.

$$\text{Equation (1)}$$

$$R_{\text{match}} = \frac{1}{C_{d2}\omega_f}$$

Figure 5 shows a frequency sweep of the primary and secondary impedance, around the operating resonance mode. In order to evaluate the electrical characteristics of the PT, the lumped parameter model should be created.

Figure 5: FEM simulation of the PT primary and secondary impedance magnitude, with the opposite side shorted.

The lumped parameters are calculated from the primary and secondary impedance resonance and anti-resonance, plus a DC impedance measurement, as described in detail in [13]. Through the FEM simulation of the PT impedance Figure 5, the equivalent parameters of Table 1 are found.

<table>
<thead>
<tr>
<th>R</th>
<th>C</th>
<th>L</th>
<th>C_{d1}</th>
<th>C_{d2}</th>
<th>1/n</th>
</tr>
</thead>
<tbody>
<tr>
<td>114nΩ</td>
<td>9.8nF</td>
<td>609μH</td>
<td>91.7nF</td>
<td>17.5pF</td>
<td>93.5</td>
</tr>
</tbody>
</table>

Table 1: PT equivalent lumped parameters obtained through FEM simulations.

From Table 1 it can be seen that the PT has a native high gain, which is good for this application. The gain is mainly determined by the thickness of the primary layers, but of course the primary section size also affects the gain.

$$\text{Equation (2)}$$

$$V_p = \frac{1}{n^2} \frac{C_{d2}}{C_{d1}} \frac{32\sqrt{6}}{9\pi^2}\eta$$
Through our own experience, this equation has its shortcomings, properly because of some of the assumption in the derivation, which is demonstrated in detail in [7]. But it has shown to predict soft switching when working with factors above approximately 1.4 and it is very simple and straightforward to use, compared to the one derived in [7]. Equation (2) is the maximal obtainable soft switching capability, which is located slightly above the resonance frequency, where the series resonance network becomes inductive and contains enough resonating energy, to charge and discharge \( C_{d1} \), if the soft switching factor is above 1.4.

The following PT properties of Table 2 are found from the equivalent parameters of Table 1 and the index “ZVS” is referring to that the PT is operating at its maximum ZVS point.

\[
\eta_{\text{match}} = 1 - \frac{2RC_{d2}}{n^2\sqrt{LC}}
\] (3)

The following PT properties of Table 2 are found from the equivalent parameters of Table 1 and the index “ZVS” is referring to that the PT is operating at its maximum ZVS point.

<table>
<thead>
<tr>
<th>( V'_p )</th>
<th>( A_{ZVS} )</th>
<th>( P_{ZVS} )</th>
<th>( R_{\text{match}} )</th>
<th>( \eta )</th>
<th>( V_{\text{out,rms}} )</th>
</tr>
</thead>
<tbody>
<tr>
<td>1.45</td>
<td>75.3</td>
<td>3.79W</td>
<td>138k( \Omega )</td>
<td>0.986</td>
<td>728V</td>
</tr>
</tbody>
</table>

Table 2: PT equivalent lumped parameter model performance properties.

Evaluating these properties it can be seen that it has a sufficient high ZVS factor of 1.45, which enables the inductor-less operation, a high efficiency and a high gain. The high gain results in a 728V rms output voltage, into a matched load, with a PT modulation voltage of 9.67V rms. The PT modulation voltage is the first harmonic, of the 24V input voltage, as derived in [13].

3 Experimental results

In the following section the functionality and properties of the received prototype PT’s are verified.

Figure 7 shows an impedance measurement of one of the prototype PT’s and from these measurements the equivalent lumped parameters of Table 3 and the performance properties of Table 4 are calculated.

<table>
<thead>
<tr>
<th>R</th>
<th>C</th>
<th>L</th>
<th>C(_{d1})</th>
<th>C(_{d2})</th>
<th>(1/n)</th>
</tr>
</thead>
<tbody>
<tr>
<td>462n( \Omega )</td>
<td>6.74nF</td>
<td>923( \mu )H</td>
<td>112nF</td>
<td>24.8pF</td>
<td>88.6</td>
</tr>
</tbody>
</table>

Table 3: Prototype PT equivalent lumped parameters obtained through impedance measurements.

<table>
<thead>
<tr>
<th>( V'_p )</th>
<th>( A_{ZVS} )</th>
<th>( P_{ZVS} )</th>
<th>( R_{\text{match}} )</th>
<th>( \eta )</th>
<th>( V_{\text{out,rms}} )</th>
</tr>
</thead>
<tbody>
<tr>
<td>1.43</td>
<td>67.5</td>
<td>4.23W</td>
<td>100k( \Omega )</td>
<td>0.933</td>
<td>653V</td>
</tr>
</tbody>
</table>

Table 4: Prototype PT equivalent lumped parameter model performance properties.

Figure 8 shows the PT operating with a half-bridge voltage of 20V and with a matched resistive load. From the input voltage waveform, it can clearly be seen that the half-bridge is operating under ZVS, which verifies the design soft switching capability. Looking at the output voltage it resembles a nice sine wave, with a peak voltage of
Having a high gain of 68, enabling the generation of high output voltages.

**Acknowledgements**

Finally we would like to thanks Noliac A/S for the production of prototype PT’s, as well as general PT design support. We would also like to thanks Danfoss PolyPower A/S for supplying the application and EAP actuators.

**References**


